

Injection Locked Gunn Diode Oscillators

FEATURES:

- High output power
- Moderate gain and bandwidth
- CW operation
- Frequency up to 110GHz

APPLICATIONS:

- Power amplification
- Local oscillators
- Multiplier drivers
- Subsystems

DESCRIPTION:

CIL Series

CIL series CW injection-locked Gunn oscillators are alternatives to HEMT device and IMPATT diode based stable amplifiers, especially at high millimeterwave frequencies. The operating frequency and power output of these oscillators are up to 110 GHz and 24 dBm. The spectrum purity of the output signal is injected signal dependent. There is an output free running signal in the absence of an input injection signal. The oscillators are provided with integral circulators and optional DC voltage regulator. An optional heater is provided to achieve better temperature stability. For higher gain, broader locking bandwidth and higher output, multi-stage and multi-diodes configurations are used.

Frequency Input Output Locking **Bias Voltage** Bias Current Waveguide Power Range Power Range Range Bandwidth Range Size (GHz) (dBm) (dBm, Min) (GHz, Max) (Volts) (A) 26.5-40 0 to 10 24 1.5 4-12 0.3-2.5 WR-28 33-50 23 2.0 0.3-2.0 WR-22 0 to 10 4-11 40-60 0 to 10 22 2.0 3-10 0.3-2.0 WR-19 50-75 0 to 10 20 2.0 3-10 0.3-1.5 WR-15 60-90 0 to 10 19 2.0 3-10 0.25-1.5 WR-12 19 2.0 4-10 0.25-1.5 75-110 0 to 10 WR-10 HOW TO ORDER:

SPECIFICATIONS:



Example: To order a 59-60 GHz injection locked Gunn oscillator with WR-15 waveguide interface, and 17 dBm output power, specify CIL-15596017-XX.

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